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CONTENTS

15 JULY 1996-I

Subject Matter Categories for Physical Review B	iiii
Editorial Policies and Practices of Physical Review B	iv
General Information for Contributors	vii
Guidelines for Estimating Length for Physical Review B	x

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Linear-response calculation of the Coulomb pseudopotential μ^* for Nb	1419
Keun-Ho Lee and K. J. Chang	
Magnetic character of the deformable jellium	1423
M. A. Ortíz, R. M. Méndez-Moreno, M. Moreno, and S. Orozco	
Pseudopotentials including semicore states, with an application to barium, α -cerium, and thorium	1427
T. Charpentier, G. Zérah, and N. Vast	
Distribution of level curvatures for the Anderson model at the localization-delocalization transition	1431
C. M. Canali, Chaitali Basu, W. Stephan, and V. E. Kravtsov	
Thermodynamics of metal-insulator systems: The two-fluid model in the presence of a magnetic field	1435
M. J. R. Hoch and C. Kasl	
Quantum phase transition and long-range order in the ground state of a lattice of pseudospins coupled with optic phonons	1439
H. Zheng and S. Y. Zhu	
Effects of impurities and temperature on the thermal hysteresis of Ohmic resistance in Tl-doped blue bronze	1443
Wang Xue-mei and Zhang Dian-lin	
Momentum-distribution critical exponents for the one-dimensional large- U Hubbard model in the thermodynamic limit	1447
Shaojin Qin and Lu Yu	
Electronic structure and optical properties of the $B_{12}O_2$ crystal	1451
Dong Li and W. Y. Ching	
Electronic structure, electronic decay, and desorption processes of molecular solid $SiCl_4$ following core-level excitation	1455
J. M. Chen, R. Klauser, S. C. Yang, Y. J. Hsu, S. I. Cheng, and C.-R. Wen	

Semiconductors I: bulk

Defect-induced nucleation and growth of amorphous silicon	1459
Laurent J. Lewis and Risto M. Nieminen	
Calculations of the ground-state energy for strong- and intermediate-coupling exciton-phonon systems	1463
Wang Yi, Wang Kelin, and Wan Shaolong	
Magnetopolaron effect on shallow indium donors in CdTe	1467
M. Grynberg, S. Huant, G. Martinez, J. Kossut, T. Wojtowicz, G. Karczewski, J. M. Shi, F. M. Peeters, and J. T. Devreese	
Disorder and persistent photoconductivity in $Zn_xCd_{1-x}Se$ semiconductor alloys	1471
M. Smith, J. Y. Lin, and H. X. Jiang	



(Continued)

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